



N 沟道增强型场效应晶体管

N-CHANNEL MOSFET

FHP10N60A/ FHF10N60A

主要参数 MAIN CHARACTERISTICS

ID	10A
VDSS	600V
Rdson-typ(@Vgs=10V)	0.68Ω
Qg-typ	45nC

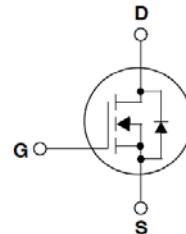
用途 APPLICATION

高频开关电源	High efficiency switch mode power supplies
电子镇流器	Electronic ballast
LED 电源	LED power supply

封装形式 Package



等效电路 Equivalent Circuit



绝对最大额定值 ABSOLUTE RATINGS (Tc=25°C)

项目 Parameter	符号 Symbol	数值 Value		单位 Unit
		FHP10N60A	FHF10N60A	
最高漏极一源极直流电压 Drain-Source Voltage	VDS	600		V
连续漏极电流* Drain Current -continuous *	ID (TC=25°C)	10*		A
	ID (TC=100°C)	6.2*		A
最大脉冲漏极电流 (注 1) Drain Current – pulse (note 1)	IDM	40*		A
最高栅源电压 Gate-Source Voltage	VGS	±20		V
单脉冲雪崩能量 (注 2) Single Pulsed Avalanche Energy (note 2)	EAS	600		mJ
雪崩电流 (注 1) Avalanche Current (note 1)	IAR	10		A
重复雪崩能量 (注 1) Repetitive Avalanche Current (note 1)	EAR	17.8		mJ
二极管反向恢复最大电压变化速率 (注 3) Peak Diode Recovery dv/dt (note 3)	dv/dt	4.5		V/ns
耗散功率 Power Dissipation	PD (TC=25°C)	156	50	W
	-Derate above 25°C	1.43	0.48	W/°C
最高结温及存储温度 Operating and Storage Temperature Range	TJ, TSTG	150, -55 to 150		°C
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	TL	300		°C

*漏极电流由最高结温限制 Drain current limited by maximum junction temperature

电特性 ELECTRICAL CHARACTERISTICS

项目 Parameter	符号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单位 Units	
关态特性 Off -Characteristics							
漏一源击穿电压 Drain-Source Voltage	BVDSS	ID=250μA, VGS=0V	600	-	-	V	
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	ΔBVDSS/Δ TJ	ID=250μA, referenced to 25°C	-	0.68	-	V/°C	
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	IDSS	VDS=650V,VGS=0V, TC=25°C	-	-	1	μA	
		VDS=520V, TC=125°C	-	-	100	μA	
栅极体漏电流 Gate-body leakage current	IGSS (F/R)	VDS=0V, VGS =±30V	-	-	±100	μA	
通态特性 On-Characteristics							
阈值电压 Gate Threshold Voltage	VGS(th)	VDS = VGS , ID=250μA	2.0	-	4.0	V	
静态导通电阻 Static Drain-Source On-Resistance	RDS(ON)	VGS =10V , ID=5A	-	0.68	0.85	Ω	
动态特性 Dynamic Characteristics							
正向跨导 Forward Trans conductance	gfs	VDS=15V, ID =5A		8		S	
输入电容 Input capacitance	Ciss	VDS=25V, VGS =0V, f=1.0MHz	-	1570	-	pF	
输出电容 Output capacitance	Coss		-	167	-		
反向传输电容 Reverse transfer capacitance	Crss		-	30	-		
开关特性 Switching Characteristics							
延迟时间 Turn-On delay time	td(on)	VDS=300V, ID=5A, RG=25Ω (note 4, 5)	-	34.8	-	ns	
上升时间 Turn-On rise time	tr		-	121	-	ns	
延迟时间 Turn-Off delay time	td(off)		-	65.6	-	ns	
下降时间 Turn-Off Fall time	tf		-	59.6	-	ns	
栅极电荷总量 Total Gate Charge	Qg	VDS =480V , ID=5A , VGS =10V (note 4, 5)	-	37.2	-	nC	
栅一源电荷 Gate-Source charge	Qgs		-	6.9	-	nC	
栅一漏电荷 Gate-Drain charge	Qgd		-	21.1	-	nC	
漏一源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings							
正向最大连续电流 Maximum Continuous Drain -Source Diode Forward Current	IS		-	-	10	A	
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current	ISM		-	-	40	A	
正向压降 Drain-Source Diode Forward Voltage	VSD	VGS=0V, IS=10A	-	-	1.4	V	
反向恢复时间 Reverse recovery time	trr	VGS=0V, IS=5A ,dIF/dt=100A/μs (note 4)	-	420	-	ns	
反向恢复电荷 Reverse recovery charge	Qrr		-	4.2	-	μC	

热特性 THERMAL CHARACTERISTIC

项目 Parameter	符号 Symbol	FHP10N60A	FHF10N60A	单位 Unit
结到管壳的热阻 Thermal Resistance, Junction to Case	R _{th(j-c)}	0.8	2.5	°C/W
结到环境的热阻 Thermal Resistance, Junction to Ambient	R _{th(j-A)}	62.5	62.5	°C/W

注释:

Notes:

- 1: 脉冲宽度由最高结温限制
- 2: L=10mH, I_D=10A, V_{DD}=48V, R_G=25 Ω,起始结温 T_J=25°C
- 3: I_{SD} ≤10A,di/dt ≤200A/μs,V_{DD}≤BVDSS,起始结温 T_J=25°C
- 4: 脉冲测试: 脉冲宽度 ≤300μs,占空比≤2%
- 5: 基本与工作温度无关

- 1: Pulse width limited by maximum junction temperature
- 2: L=10mH, ID=10A, V_{DD}=48V, R_G=25 Ω,Start TJ=25°C.
- 3: ISD ≤10A,di/dt ≤200A/μs,VDD≤BVDSS, Starting TJ=25°C
- 4: Pulse Test: Pulse Width ≤300μs,Duty Cycle≤2%
- 5: Essentially independent of operating temperatur

特性曲线

ELECTRICAL CHARACTERISTICS (curves)

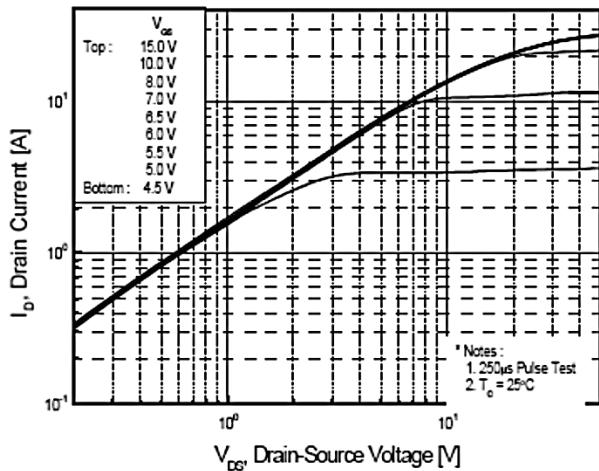


图 1 输出特性曲线, $T_c=25^\circ\text{C}$

Fig1 Typical Output Characteristics, $T_c=25^\circ\text{C}$

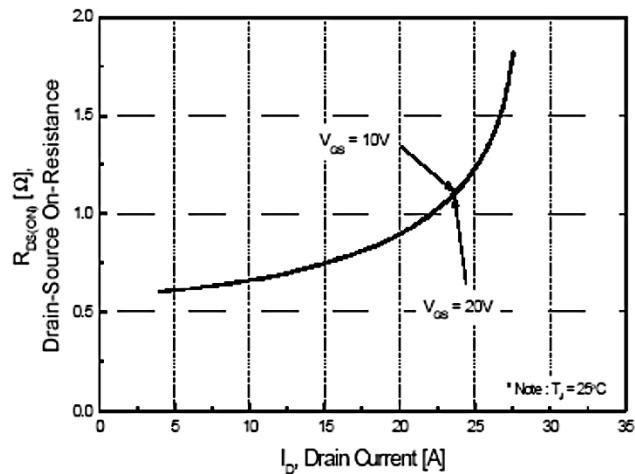


图 2 导通电阻与漏极电流和栅极电压曲线

Fig2 On-Resistance Vs.Drain Current and Gate Voltage

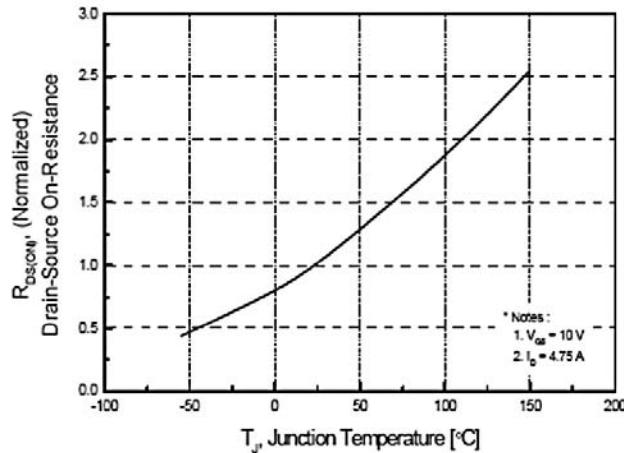


图 3 导通电阻与温度曲线

Fig3 Normalized On-Resistance Vs. Temperature

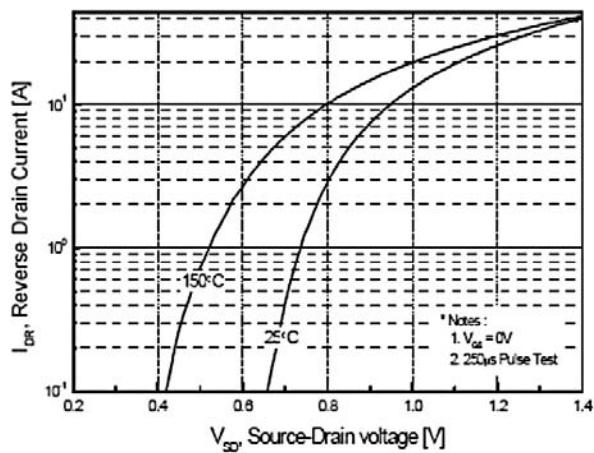


图 4 二极管正向电压曲线

Fig4 Typical Source-Drain Diode Forward Voltage

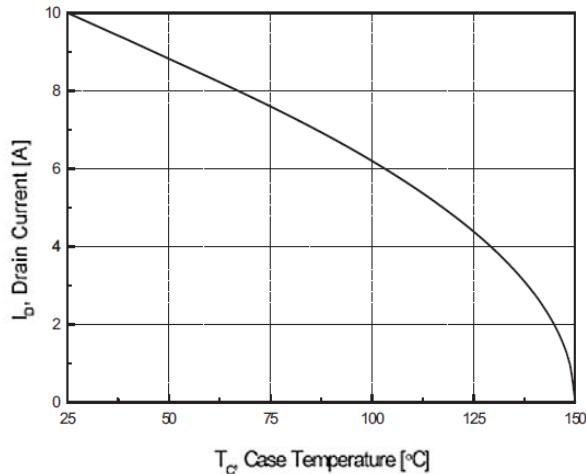


图 5 最大漏极电流与壳温曲线

Fig5 Maximum Drain Current Vs.Case Temperature

特性曲线

ELECTRICAL CHARACTERISTICS (curves)

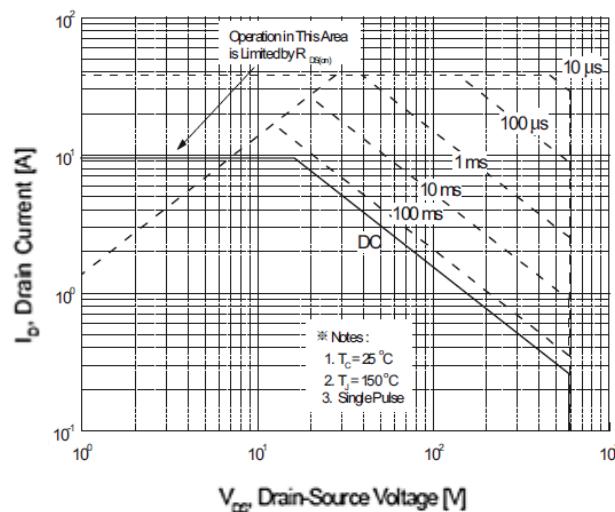


图 6-1 (TO-220)

最大安全工作区曲线

Fig6-1 Maximum Safe Operating Area

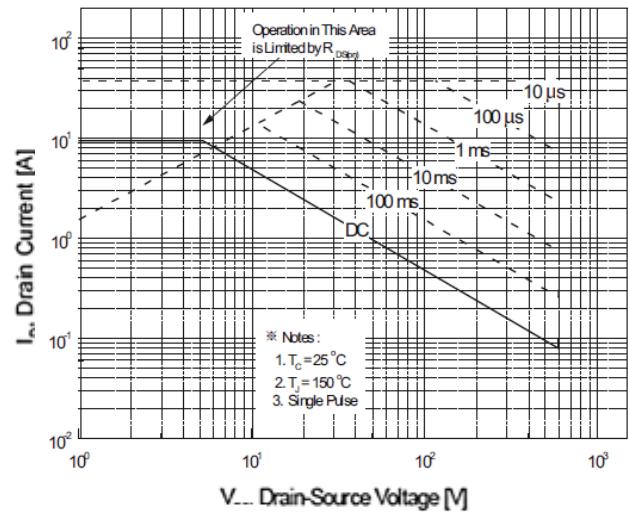
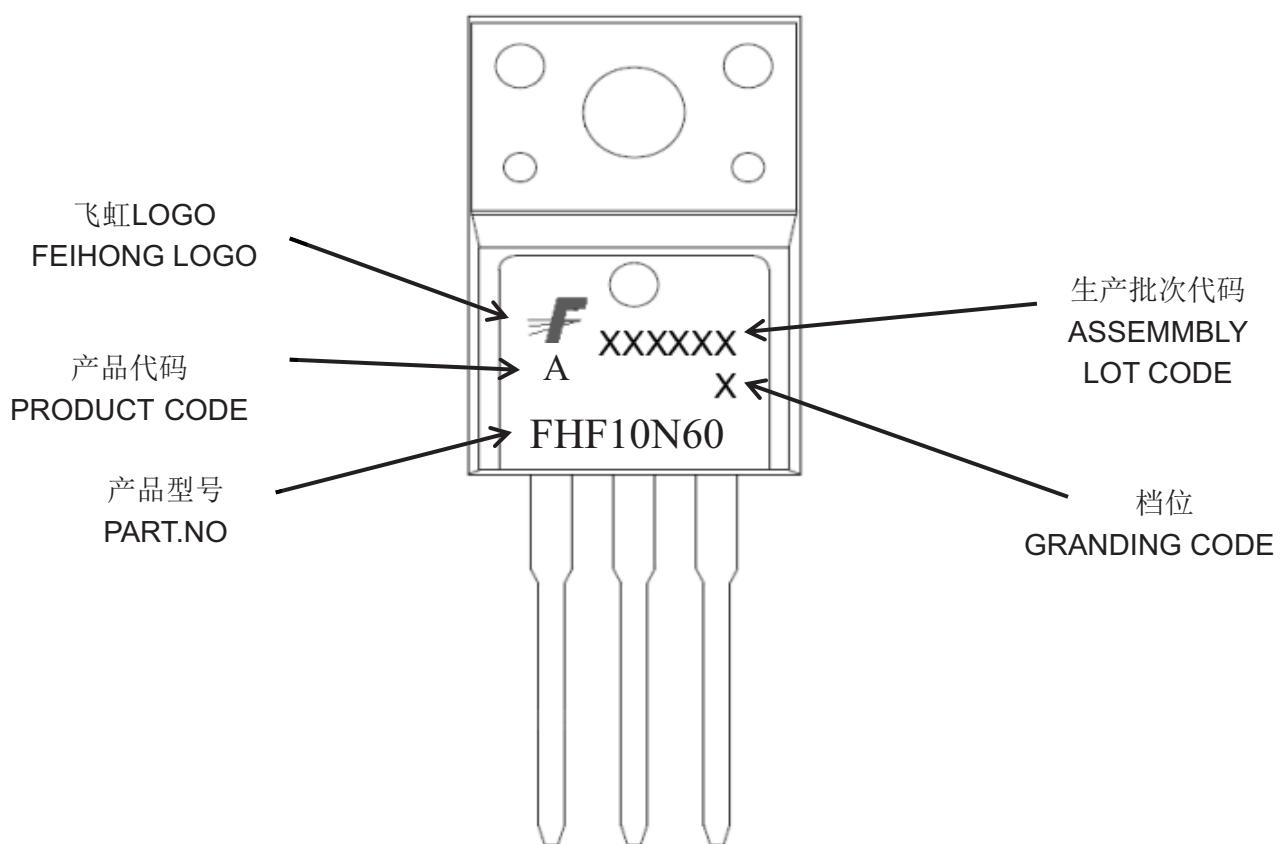
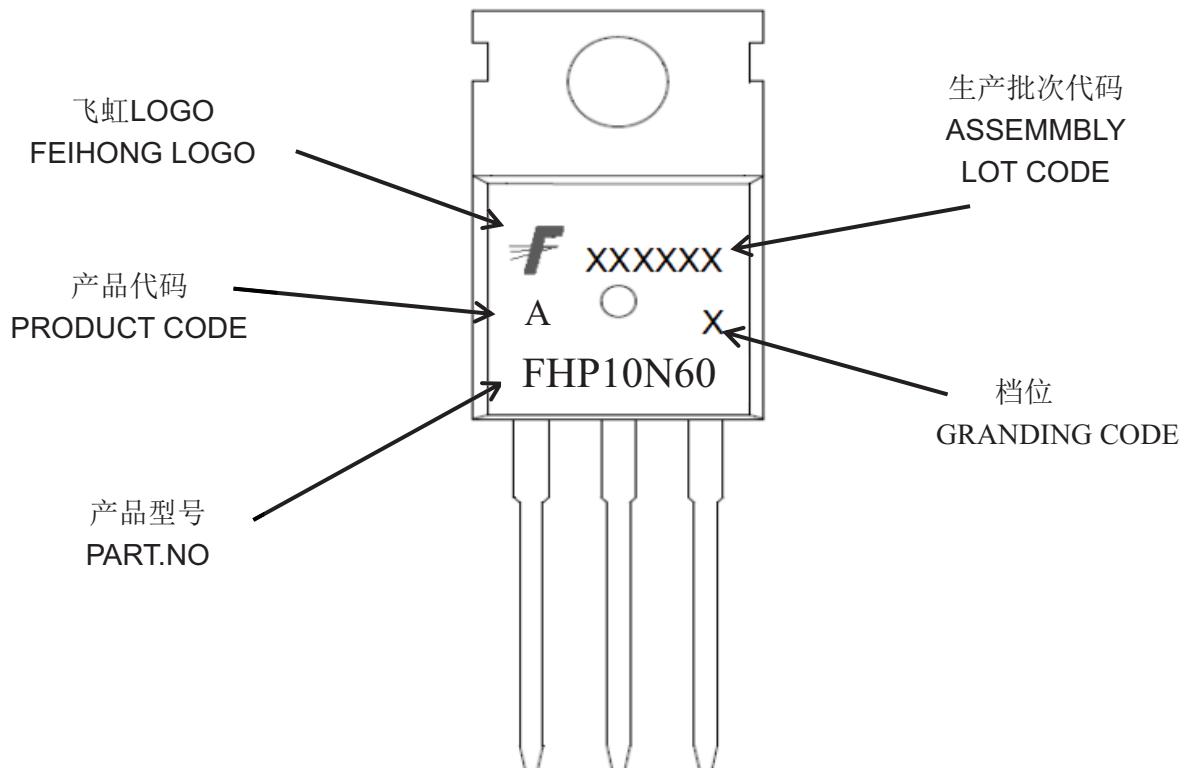


图 6-1 (TO-220F)

最大安全工作区曲线

Fig6 -2Maximum Safe Operating Area

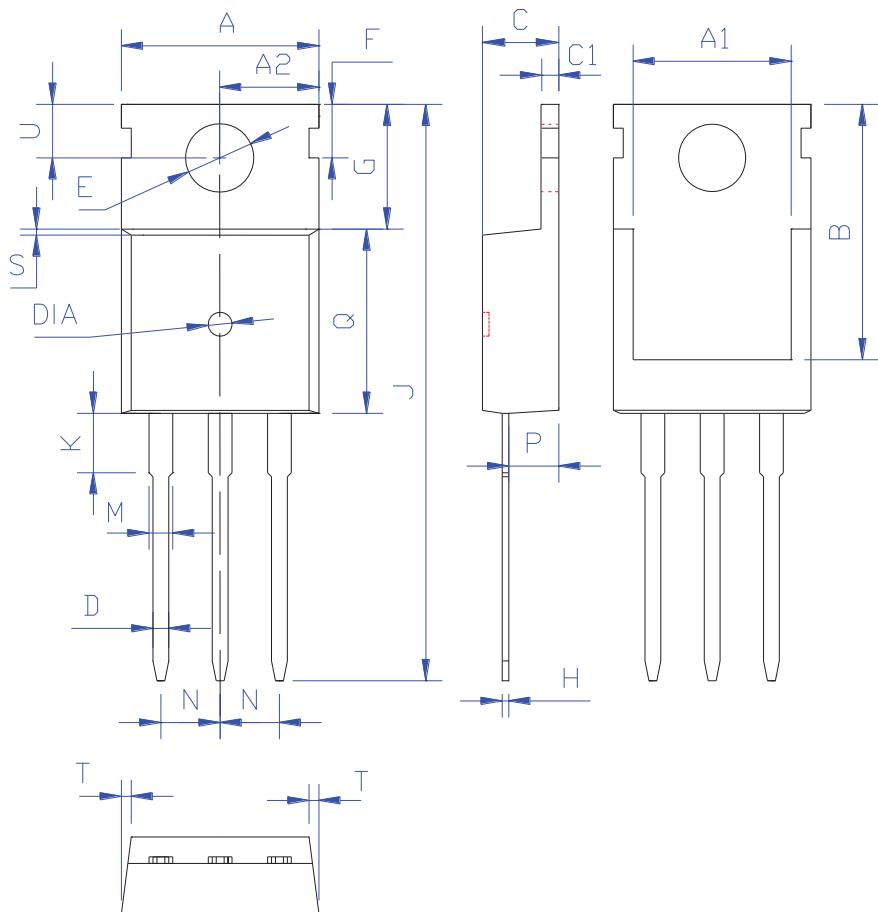
印记 Marking



外形尺寸:

Package Dimension:

TO-220



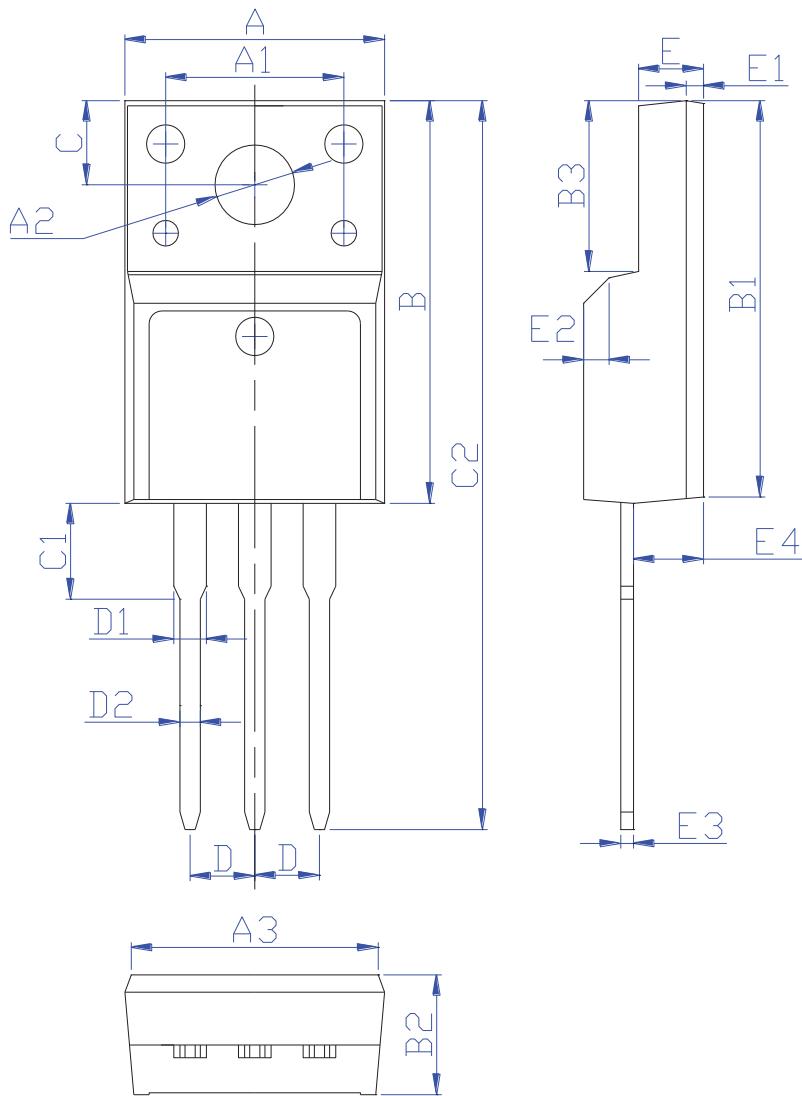
DIM	MILLIMETERS
A	10.00±0.30
A1	8.00±0.30
A2	5.00±0.30
B	13.20±0.40
C	4.50±0.20
C1	1.30±0.20
D	0.80±0.20
E	3.50±0.20
F	3.00±0.30
G	5.50±0.40
H	0.50±0.20
J	28.88±0.50
K	3.00±0.30
M	1.30±0.30
N	Typical 2.54
P	2.40±0.40
Q	9.20±0.40
S	0.25±0.15
T	0.25±0.15
U	2.80±0.30
DIA	宽 1.50±0.10 深 0.50 MAX

(Units: mm)

外形尺寸:

Package Dimension:

TO-220F



DIM	MILLIMETERS
A	10.16±0.30
A1	7.00±0.20
A2	3.12±0.20
A3	9.70±0.30
B	15.90±0.50
B1	15.60±0.50
B2	4.70±0.30
B3	6.70±0.30
C	3.30±0.25
C1	3.25±0.30
C2	28.70±0.50
D	Typical 2.54
D1	1.47 (MAX)
D2	0.80±0.20
E	2.55±0.25
E1	0.70±0.25
E2	1.0×45°
E3	0.50±0.20
E4	2.75±0.30

(Units:mm)